#### Nch 190V 10A Power MOSFET

$V_{DSS}$	190V
R <sub>DS(on)</sub> (Max.)	182mΩ
I <sub>D</sub>	±10A
P <sub>D</sub>	85W

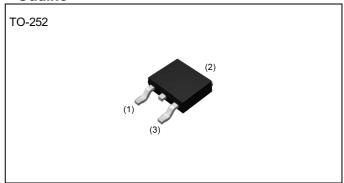
#### Features

- 1) Low on-resistance
- 2) Fast switching speed
- 3) Drive circuits can be simple
- 4) Parallel use is easy
- 5) Pb-free plating; RoHS compliant

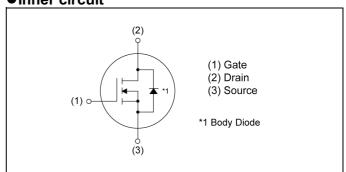
### Application

**Switching Power Supply** 

#### Outline



### •Inner circuit



Packaging specifications

Packing	Embossed Tape
Packing code	TL1
Marking	RD3S100CN
Quantity (pcs)	2500

# ● **Absolute maximum ratings** (T<sub>a</sub> = 25°C ,unless otherwise specified)

Parameter	Symbol	Value	Unit
Drain - Source voltage	V <sub>DSS</sub>	190	V
Continuous drain current (T <sub>c</sub> = 25°C)	I <sub>D</sub> *1	±10	А
Pulsed drain current	I <sub>DP</sub> *2	±40	А
Gate - Source voltage	$V_{GSS}$	±20	V
Avalanche current, single pulse	I <sub>AS</sub> *3	5.0	Α
Avalanche energy, single pulse	E <sub>AS</sub> *3	8.33	mJ
Power dissipation (T <sub>c</sub> = 25°C)	P <sub>D</sub>	85	W
Junction temperature	Tj	150	°C
Operating junction and storage temperature range	T <sub>stg</sub>	-55 to +150	°C

#### ●Thermal resistance

Downwortow	Cymah al	Values			1.1:4
Parameter	Symbol	Min.	Тур.	Max.	Unit
Thermal resistance, junction - case	R <sub>thJC</sub>	-	-	1.46	°C/W
Thermal resistance, junction - ambient	R <sub>thJA</sub>	-	-	147	°C/W
Soldering temperature, wavesoldering for 10s	T <sub>sold</sub>	-	-	265	°C

# ●Electrical characteristics (T<sub>a</sub> = 25°C)

Darameter	Cumb al	Conditions	Values			Unit	
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Offic	
Drain - Source breakdown voltage	$V_{(BR)DSS}$ $V_{GS} = 0V, I_D = 1mA$		190	-	-	٧	
		V <sub>DS</sub> = 190V, V <sub>GS</sub> = 0V					
Zero gate voltage drain current	I <sub>DSS</sub>	$T_j = 25^{\circ}C$	-	-	10	μA	
		T <sub>j</sub> = 125°C	-	-	100		
Gate - Source leakage current	I <sub>GSS</sub>	$V_{GS} = \pm 20V, V_{DS} = 0V$	-	-	±100	nA	
Gate threshold voltage	$V_{GS(th)}$ $V_{DS} = 10V, I_D = 1mA$		0.5	-	2.5	٧	
	R <sub>DS(on)</sub> *4	V <sub>GS</sub> = 10V, I <sub>D</sub> = 5A					
		$T_j = 25^{\circ}C$	-	130	182		
Static drain - source on - state resistance		T <sub>j</sub> = 125°C	-	195	ı	mΩ	
		V <sub>GS</sub> = 4V, I <sub>D</sub> = 5A		126	100		
		T <sub>j</sub> = 25°C	-	136	190		
Gate resistance	$R_{G}$	f = 1MHz, open drain	-	4.5	-	Ω	

### ● Electrical characteristics (T<sub>a</sub> = 25°C)

Davamatar	Cymah al	Conditions	Values			Unit	
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Offic	
Forward Transfer Admittance	Y <sub>fs</sub>  *4	$ Y_{fs} ^{*4}$ $V_{DS} = 10V, I_D = 5.0A$		12	-	S	
Input capacitance	C <sub>iss</sub>	V <sub>GS</sub> = 0V	-	2000	-		
Output capacitance	C <sub>oss</sub>	V <sub>DS</sub> = 25V	-	95	-	pF	
Reverse transfer capacitance	C <sub>rss</sub>	f = 1MHz	-	60	1		
Turn - on delay time	t <sub>d(on)</sub> *4	$V_{DD} \simeq 100V$ , $V_{GS} = 10V$	-	15	-		
Rise time	t <sub>r</sub> *4	I <sub>D</sub> = 5A	-	20	-	20	
Turn - off delay time	t <sub>d(off)</sub> *4	$R_L \simeq 20\Omega$	-	140	-	ns	
Fall time	t <sub>f</sub> *4	$R_G = 10\Omega$	-	75	1		

### ● Gate charge characteristics (T<sub>a</sub> = 25°C)

Davamatar	Company of	Conditions	Values			Lloit
Parameter	Parameter Symbol Conditions		Min.	Тур.	Max.	Unit
Total gate charge	$Q_g^{*4}$	V <sub>DD</sub> ≈ 100V	-	52	-	
Gate - Source charge	Q <sub>gs</sub> *4	I <sub>D</sub> = 10A	-	5	-	nC
Gate - Drain charge	Q <sub>gd</sub> *4	V <sub>GS</sub> = 10V	-	11	-	
Gate plateau voltage	V <sub>(plateau)</sub>	V <sub>DD</sub> ≈ 100V, I <sub>D</sub> = 10A	-	2.5	-	V

<sup>\*1</sup> Limited only by maximum temperature allowed.

<sup>\*2</sup> Pw  $\leq$  10µs, Duty cycle  $\leq$  1%

<sup>\*3</sup> L  $\simeq$  500 $\mu$ H, V<sub>DD</sub> = 50V, R<sub>G</sub> = 25 $\Omega$ , starting T<sub>j</sub> = 25°C

<sup>\*4</sup> Pulsed

# ●Body diode electrical characteristics (Source-Drain) (T<sub>a</sub> = 25°C)

Parameter	Symbol	Conditions	Values			Unit	
- Farameter	Symbol	Conditions	Min.	Тур.	Max.	Offic	
Source current	I <sub>S</sub> *1	· T <sub>C</sub> = 25°C	1	-	10	Α	
Pulsed source current	l <sub>SP</sub> *2	1C - 23 C	1	-	40	Α	
Source-Drain voltage	V <sub>SD</sub> *4	$V_{GS} = 0V, I_{S} = 10A$	-	-	1.5	V	
Reverse recovery time	t <sub>rr</sub> *4		-	95	-	ns	
Reverse recovery charge	e recovery charge $Q_{rr}^{*4}$ $I_S = 5A$ $di/dt = 100A/g$		-	255	-	nC	
Peak reverse recovery current	I <sub>rr</sub>		-	5.5	-	Α	

Fig.1 Power Dissipation Derating Curve

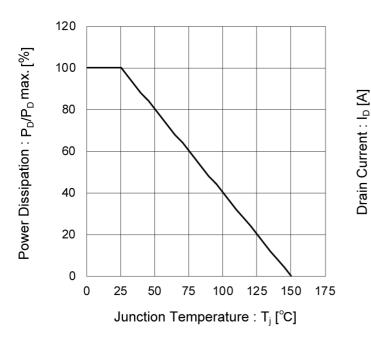


Fig.2 Maximum Safe Operating Area

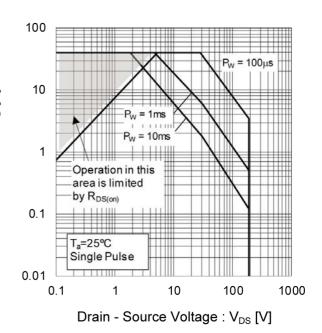
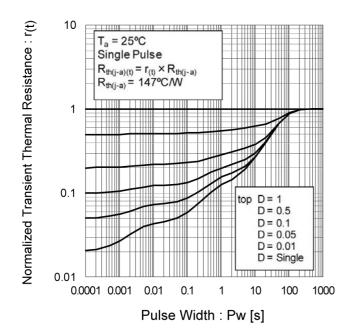


Fig.3 Normalized Transient Thermal Resistance vs. Pulse Width



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Avalanche Current : I<sub>AS</sub> [A]

#### Electrical characteristic curves

Fig.4 Avalanche Current vs. Inductive Load

Fig.5 Avalanche Energy Derating Curve vs. Junction Temperature

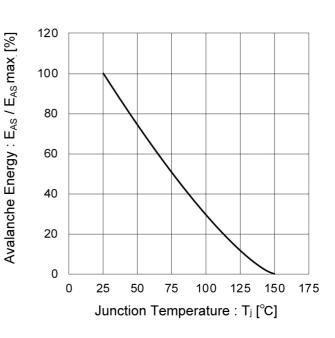
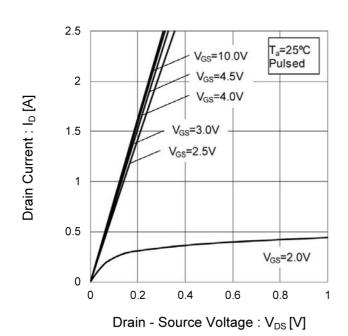


Fig.6 Typical Output Characteristics(I)



Drain Current : I<sub>D</sub> [A]

10 V<sub>GS</sub>=10.0V T<sub>a</sub>=25℃ 9 Pulsed V<sub>GS</sub>=4.5V 8 V<sub>GS</sub>=4.0V 7  $V_{GS}=3.0V$ 6 V<sub>GS</sub>=2.8V 5 4 3 2 V<sub>GS</sub>=2.0V 1 0 0 2 4 6 10

Fig.7 Typical Output Characteristics(II)

Drain - Source Voltage : V<sub>DS</sub> [V]

Fig.8 Breakdown Voltage vs. Junction Temperature

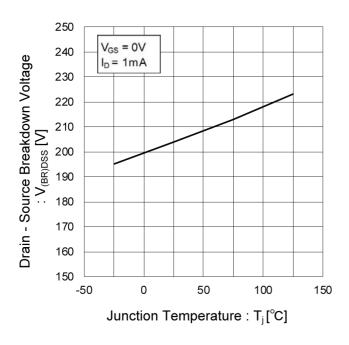


Fig.9 Typical Transfer Characteristics

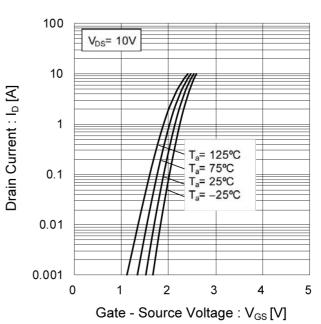


Fig.10 Gate Threshold Voltage vs. Junction Temperature

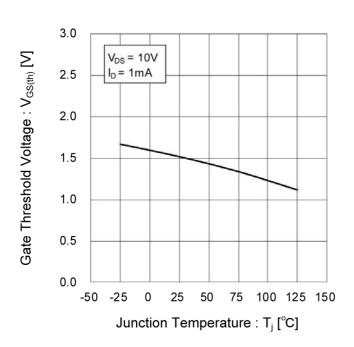


Fig.11 Transconductance vs. Drain Current

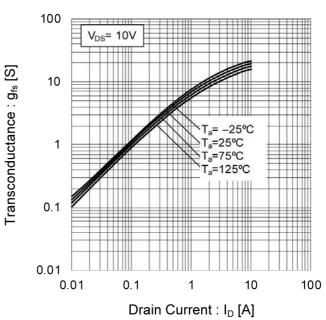


Fig.12 Static Drain - Source On - State Resistance vs. Gate Source Voltage

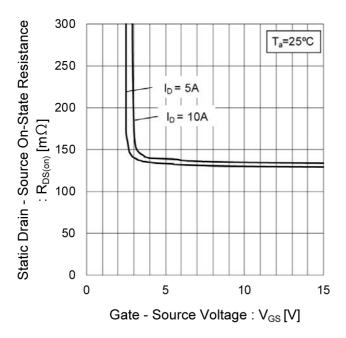


Fig.13 Static Drain - Source On - State Resistance vs. Drain Current( I )

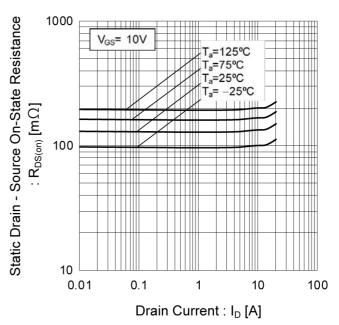


Fig.14 Static Drain - Source On - State Resistance vs. Drain Current( II )

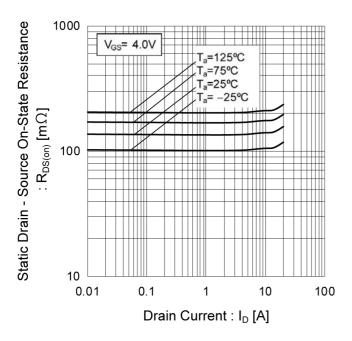


Fig.15 Static Drain - Source On - State Resistance vs. Junction Temperature

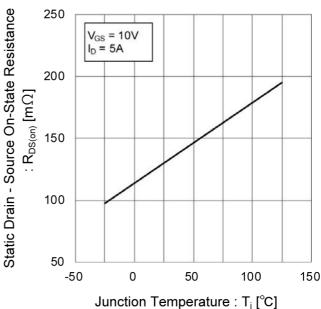


Fig.16 Source Current vs. Source-Drain Voltage

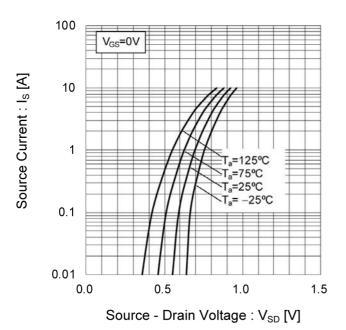


Fig.17 Source Current vs. Reverse Recovery Time

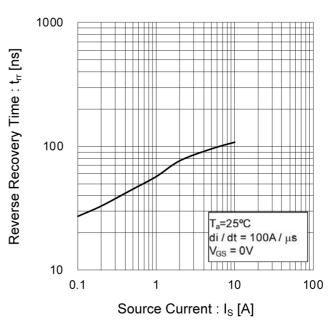


Fig.18 Typical Capacitance vs. Drain - Source Voltage

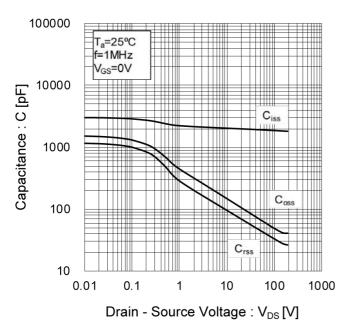


Fig.19 Switching Characteristics

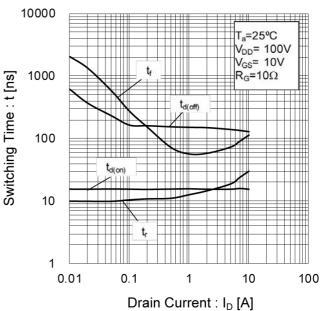
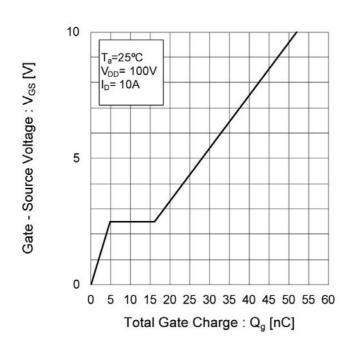


Fig.20 Dynamic Input Characteristics



#### Measurement circuits

Fig.1-1 Switching Time Measurement Circuit

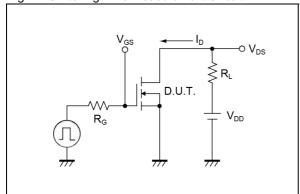


Fig.2-1 Gate Charge Measurement Circuit

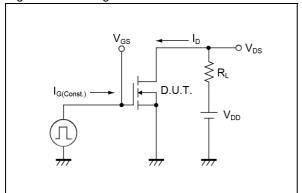


Fig.3-1 Avalanche Measurement Circuit

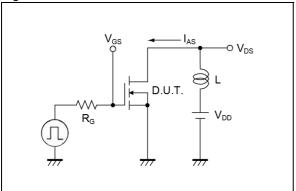


Fig.4-1 trr Measurement Circuit

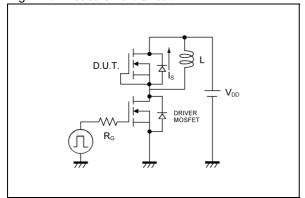


Fig.1-2 Switching Waveforms

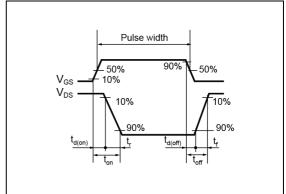


Fig.2-2 Gate Charge Waveform

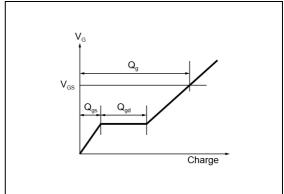


Fig.3-2 Avalanche Waveform

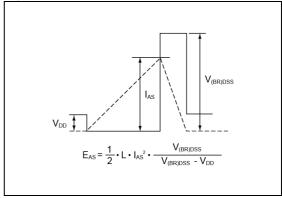
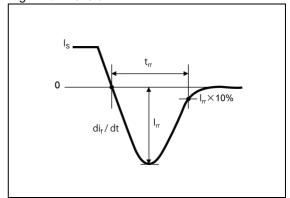
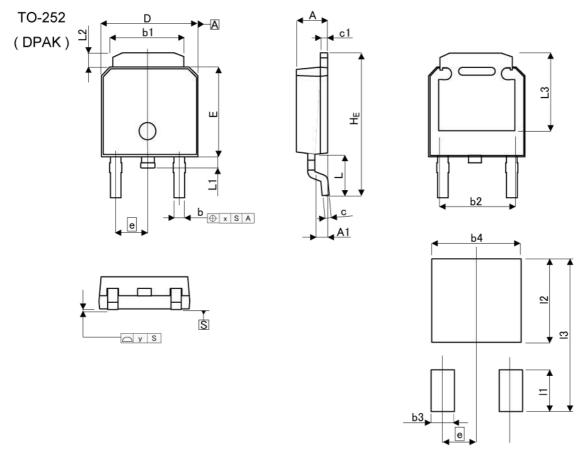


Fig.4-2 trr Waveform



#### Dimensions



Pattern of terminal position areas [Not a recommended pattern of soldering pads]

DIM	MILIMETERS		INC	HES
ן ואוט	MIN	MAX	MIN	MAX
Α	2.20	2.40	0.087	0.094
A1	0.70	1.10	0.028	0.043
b	0.60	0.90	0.024	0.035
b1	5.20	5.50	0.205	0.217
b2	4.	80	0.1	89
С	0.40	0.60	0.016	0.024
c1	0.40	0.60	0.016	0.024
D	6.40	6.80	0.252	0.268
е	2.	30	0.0	91
E	6.00	6.40	0.236	0.252
HE	9.40	10.40	0.370	0.409
L	2.	90	0.1	14
L1	0.60	1.00	0.024	0.039
L2	0.70	1.30	0.028	0.051
L3	5.	30	0.209	
х		0.25		0.010
у		0.10	(5)	0.004
DIA .	MILIME	TERS	INC	HES
DIM	MIN	MAX	MIN	MAX
b3	*	1.15	S#40	0.045
b4	-	5.55	0.750	0.219
11	-	2.77	S (#2)	0.109
12	8	5.50	(5)	0.217
13	4:	10.40	7E0	0.409

Dimension in mm/inches



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JAPAN	USA	EU	CHINA
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CLASSIV	CLASSIII	CLASSⅢ	CLASSIII

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  - [g] Use of our Products without cleaning residue of flux (Exclude cases where no-clean type fluxes is used. However, recommend sufficiently about the residue.); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
  - [h] Use of the Products in places subject to dew condensation
- 4. The Products are not subject to radiation-proof design.
- 5. Please verify and confirm characteristics of the final or mounted products in using the Products.
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- 7. De-rate Power Dissipation depending on ambient temperature. When used in sealed area, confirm that it is the use in the range that does not exceed the maximum junction temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
- 9. ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

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For details, please refer to ROHM Mounting specification

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- 1. If change is made to the constant of an external circuit, please allow a sufficient margin considering variations of the characteristics of the Products and external components, including transient characteristics, as well as static characteristics.
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This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of lonizer, friction prevention and temperature / humidity control).

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  - [b] the temperature or humidity exceeds those recommended by ROHM
  - [c] the Products are exposed to direct sunshine or condensation
  - [d] the Products are exposed to high Electrostatic
- 2. Even under ROHM recommended storage condition, solderability of products out of recommended storage time period may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is exceeding the recommended storage time period.
- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
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